



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of: Naoki SHIBATA et al.

Examiner: CHOWDHURY, TARIFUR RASHID

Serial No. 09/985,927

Filed: November 6, 2001

Group Art Unit: 2826

Title: GROUP III NITRIDE COMPOUND SEMICONDUCTOR DEVICE AND METHOD
FOR PRODUCING THE SAME

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DECLARATION UNDER 37 C.F.R. 1.55(a)

Honorable, Commissioner of Patents and Trademarks
Alexandria, VA 22313-1450

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OCT 17 2003
TO 2800 MAIL ROOM

Sir,

I, Kimihide Hashimoto, declare and say:

THAT I am a citizen of Japan residing at Shinjuku-ku,
Tokyo, Japan:

THAT I am a graduate of Yokohama National University,
Yokohama, Japan, having received the Degree of Master of
Engineering, in 1994;

THAT I am presently employed by NGB Corporation, 28th
Floor, ARK Mori Bldg., 12-32 Akasaka 1-chome, Minato-ku, Tokyo,
Japan and have been so employed since April, 1994;

THAT I understand the Japanese and English languages;
and

THAT the attached English document is a full true, faithful and accurate translation of the specification as filed of Japanese Patent Application No. Hei-11-092948 filed on March 31, 1999.

I declare further that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

A handwritten signature in black ink, consisting of several fluid, overlapping strokes that form a stylized representation of the name Kimihide Hashimoto.

Kimihide Hashimoto

September 26, 2003